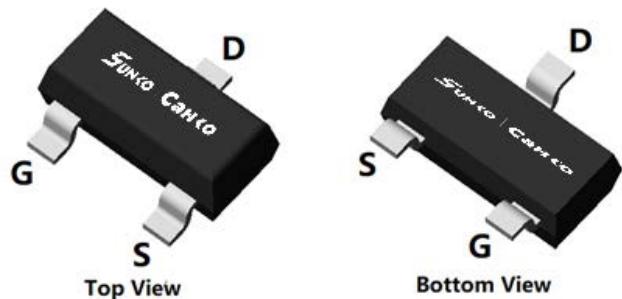
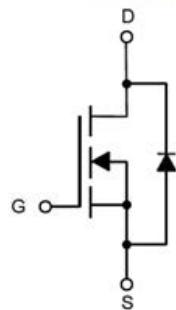


## N-Channel Enhancement Mode Field Effect Transistor


**SOT-23**


### Product Summary

- $V_{DS}$  30V
- $I_D$  5.6A
- $R_{DS(ON)}$  (at  $V_{GS}=10V$ ) <25mohm
- $R_{DS(ON)}$  (at  $V_{GS}=4.5V$ ) <31mohm
- $R_{DS(ON)}$  (at  $V_{GS}=2.5V$ ) <45mohm

### General Description

- Trench Power LV MOSFET technology
- High density cell design for low  $R_{DS(ON)}$
- High Speed switching
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

### Applications

- Battery protection
- Load switch
- Power management

### ■ Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		$V_{DS}$	30	V
Gate-source Voltage		$V_{GS}$	$\pm 12$	V
Drain Current	$T_A=25^\circ C$	$I_D$	5.6	A
	$T_A=70^\circ C$		4.5	
Pulsed Drain Current <sup>A</sup>		$I_{DM}$	23	A
Total Power Dissipation	$T_A=25^\circ C$	$P_D$	1.2	W
	$T_A=70^\circ C$		0.8	
Thermal Resistance Junction-to-Ambient <sup>B</sup>		$R_{\theta JA}$	104	$^\circ C/W$
Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~+150	$^\circ C$

### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SCL3400A	F2	3400.	3000	30000	120000	7" reel

■ Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	30			V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}$			1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS1}}$	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$			$\pm 100$	nA
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	0.65	0.9	1.5	V
Static Drain-Source On-Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=5.6\text{A}$		20	25	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=5\text{A}$		23	31	
		$V_{\text{GS}}=2.5\text{V}, I_{\text{D}}=3\text{A}$		27	45	
Diode Forward Voltage	$V_{\text{SD}}$	$I_{\text{S}}=5.6\text{A}, V_{\text{GS}}=0\text{V}$			1.2	V
<b>Dynamic Parameters</b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$		630		$\text{pF}$
Output Capacitance	$C_{\text{oss}}$			55		
Reverse Transfer Capacitance	$C_{\text{rss}}$			71		
<b>Switching Parameters</b>						
Total Gate Charge	$Q_g$	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, I_{\text{D}}=5.6\text{A}$		17.25		$\text{nC}$
Gate-Source Charge	$Q_{\text{gs}}$			2.1		
Gate-Drain Charge	$Q_{\text{gd}}$			2		
Reverse Recovery Charge	$Q_{\text{rr}}$	$I_F=5.6\text{A}, dI/dt=100\text{A/us}$		1.1		$\text{ns}$
Reverse Recovery Time	$t_{\text{rr}}$			13.1		
Turn-on Delay Time	$t_{\text{D(on)}}$			4.4		
Turn-on Rise Time	$t_r$	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, I_{\text{D}}=5.6\text{A}$ $R_{\text{GEN}}=3\Omega$		28.2		$\text{ns}$
Turn-off Delay Time	$t_{\text{D(off)}}$			16.2		
Turn-off fall Time	$t_f$			26		

A. Pulse Test: Pulse Width  $\leq 300\text{us}$ , Duty cycle  $\leq 2\%$ .B.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design, while  $R_{\theta JA}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

## ■ Typical Performance Characteristics

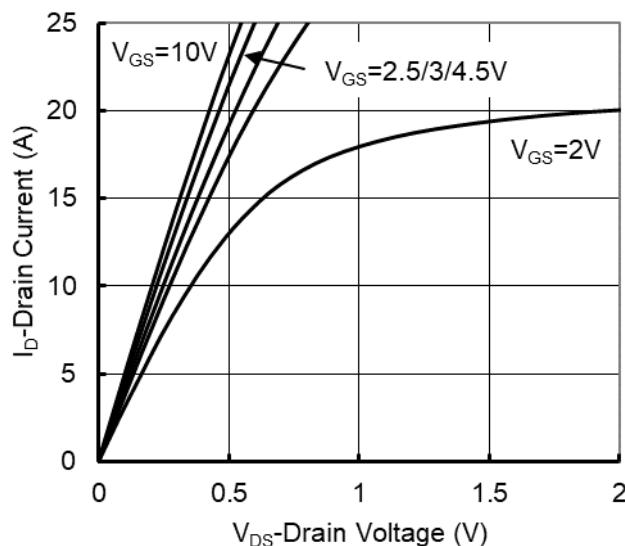


Figure 1. Output Characteristics

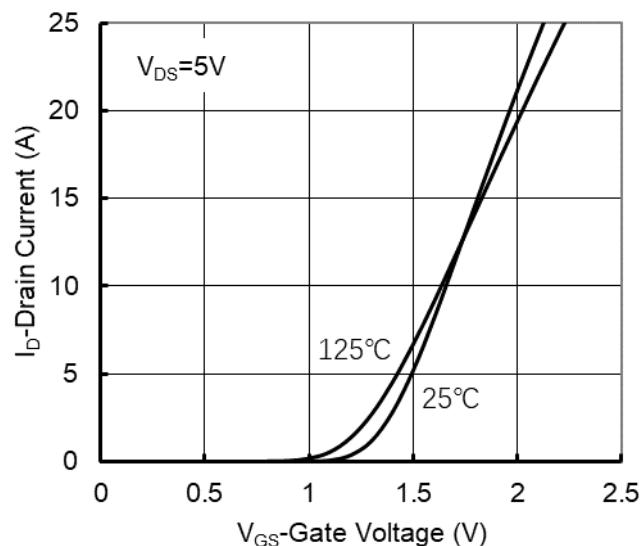


Figure 2. Transfer Characteristics

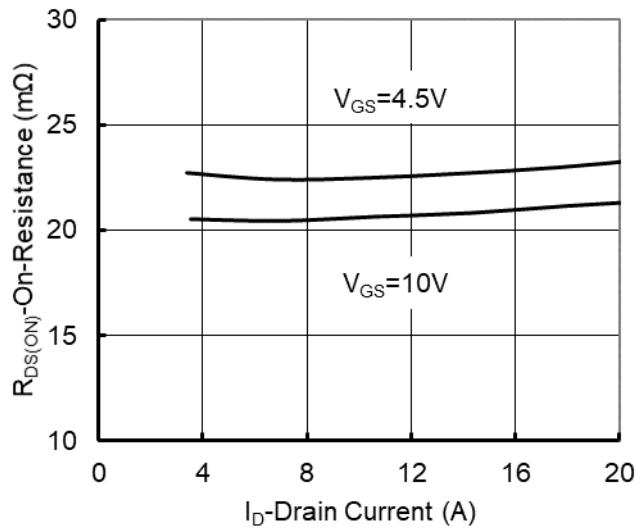


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

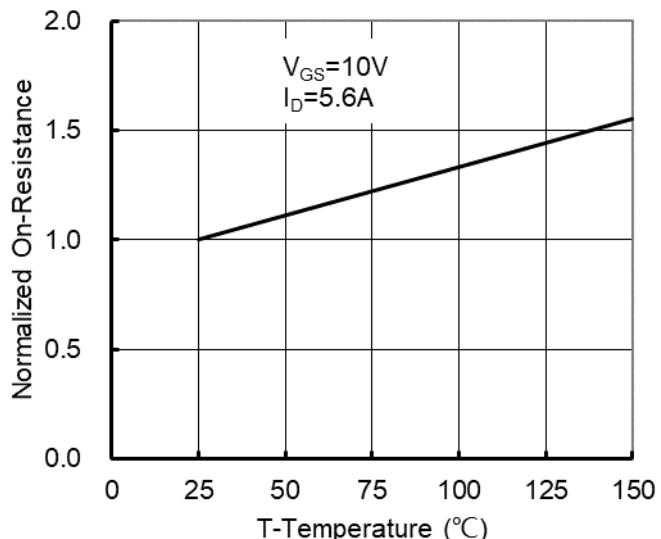


Figure 4: On-Resistance vs. Junction Temperature

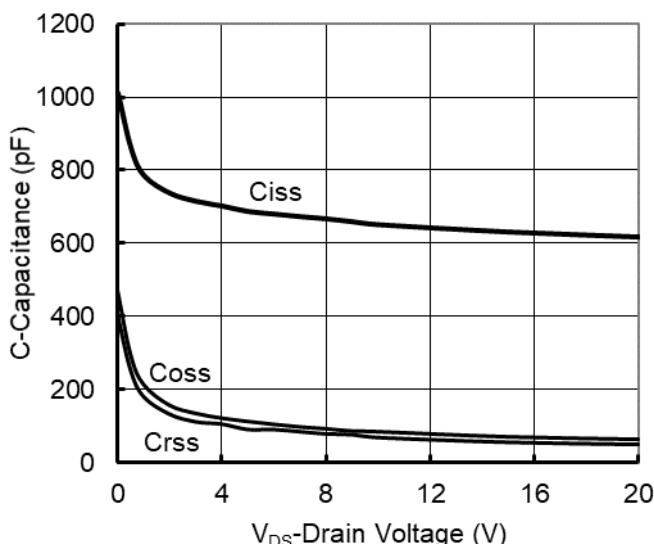


Figure 5. Capacitance Characteristics

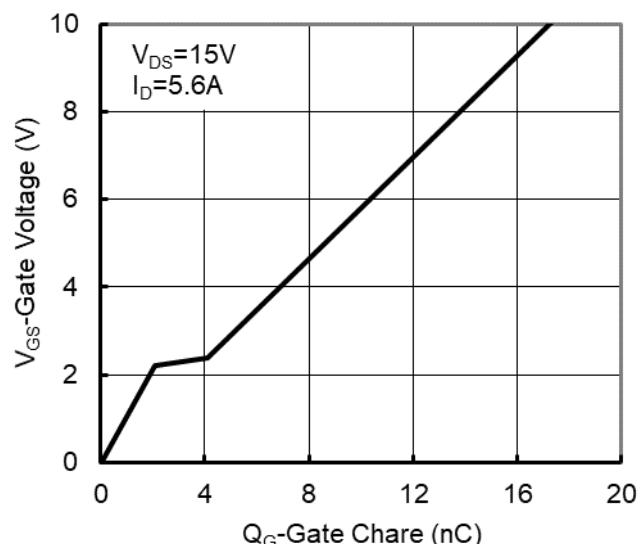


Figure 6. Gate Charge

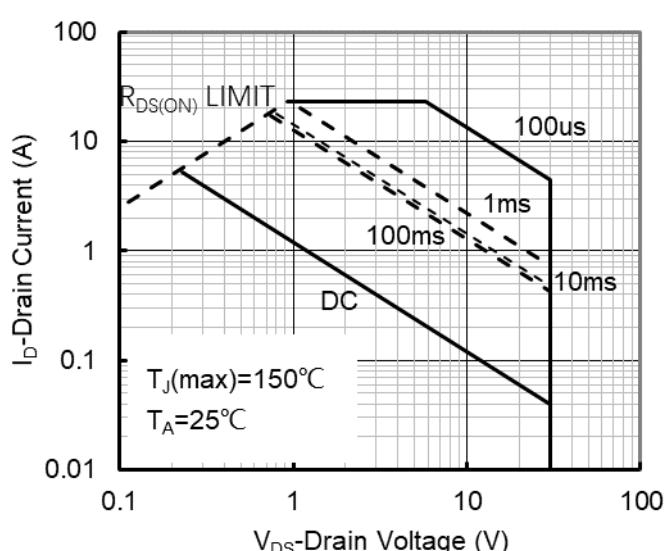


Figure 7. Safe Operation Area

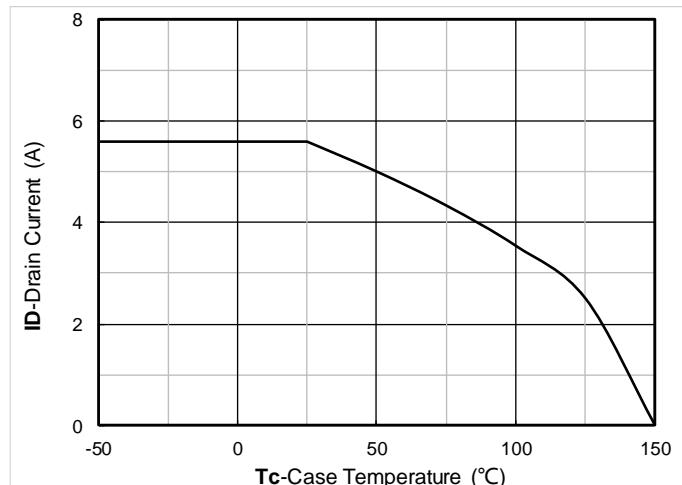


Figure 8. Current dissipation

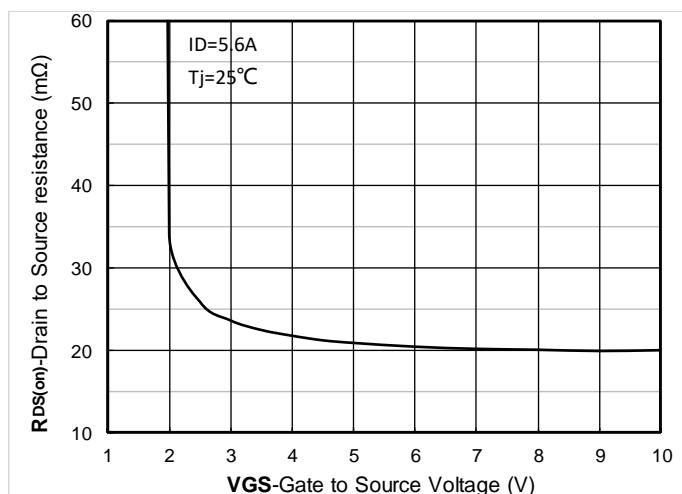


Figure 9. On-Resistance vs Gate to Source Voltage

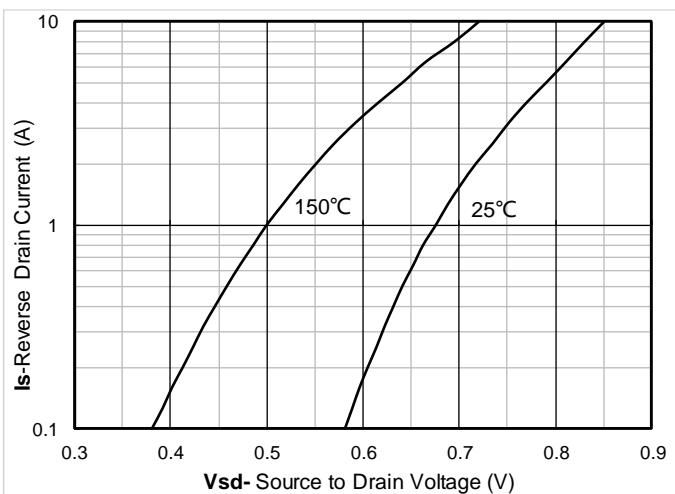


Figure 10. Forward characteristics of reverse diode

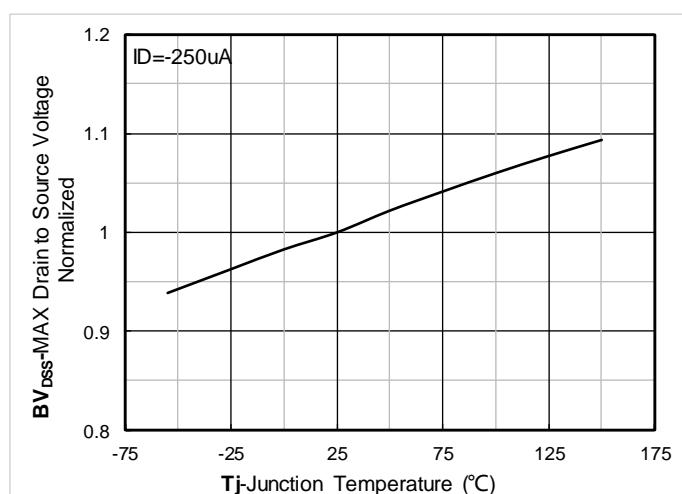


Figure 11. Normalized breakdown voltage

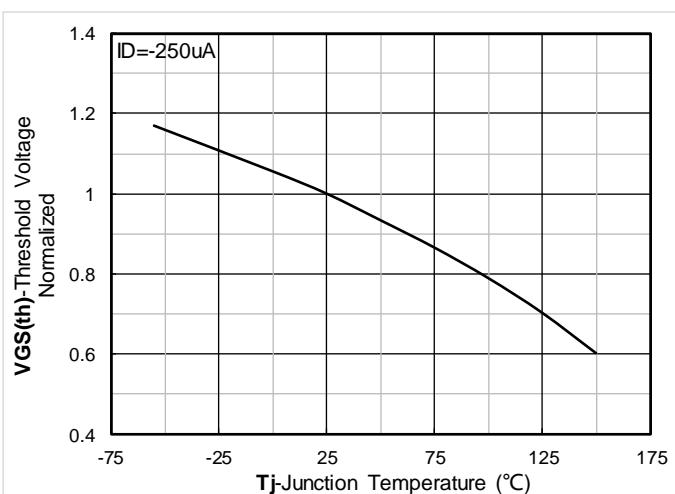


Figure 12. Normalized Threshold voltage

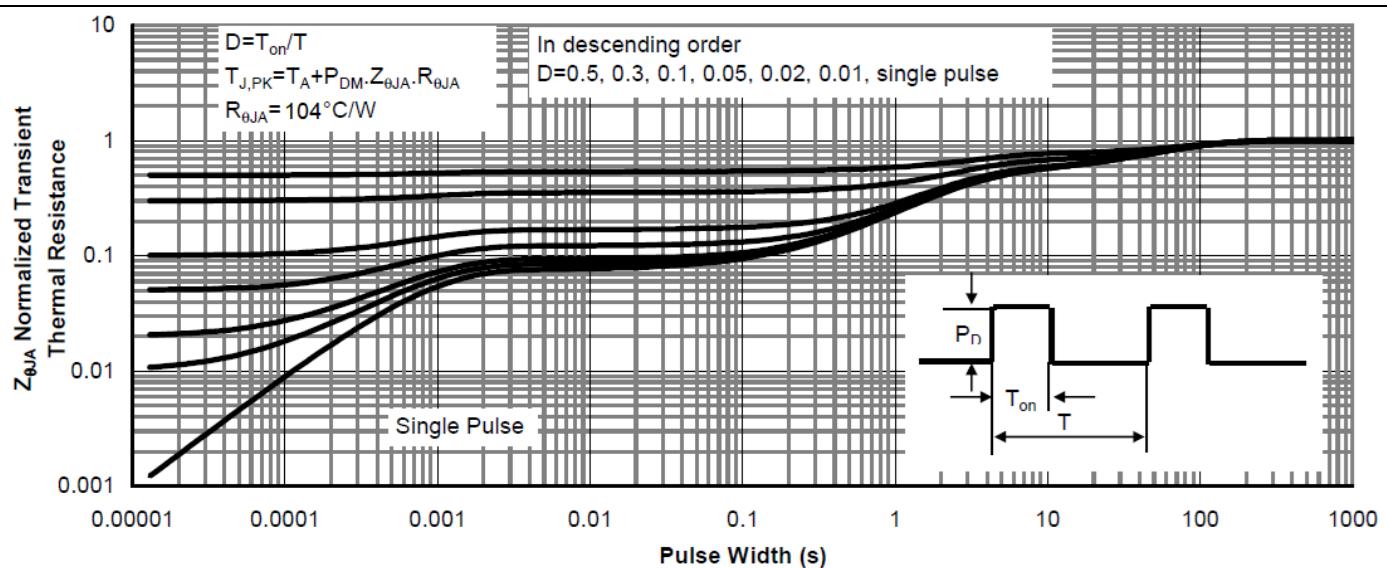
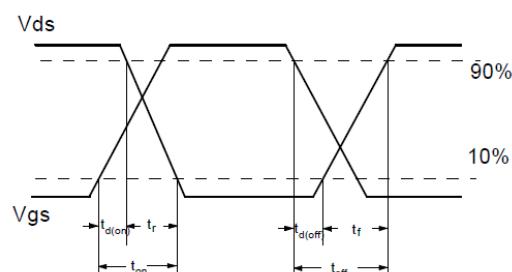
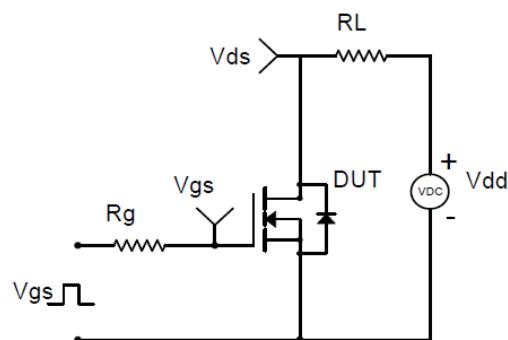
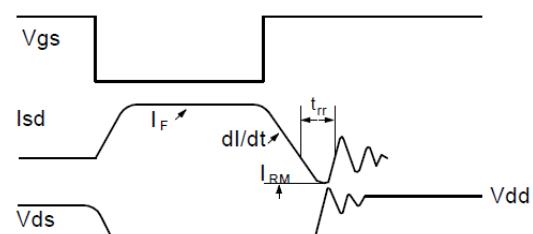
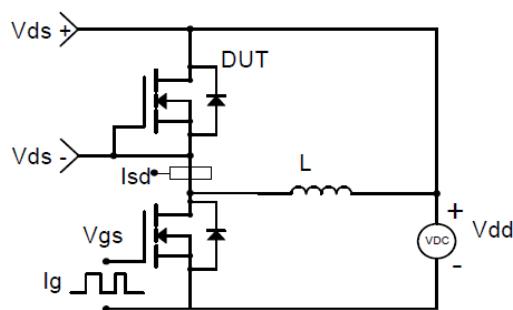


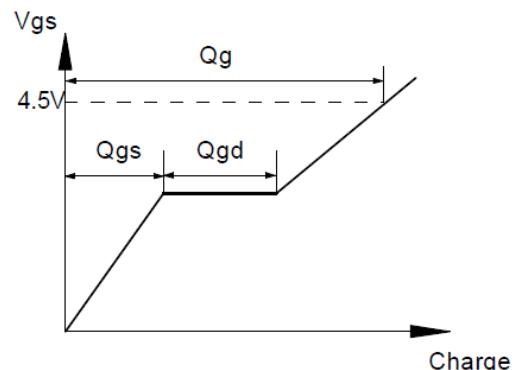
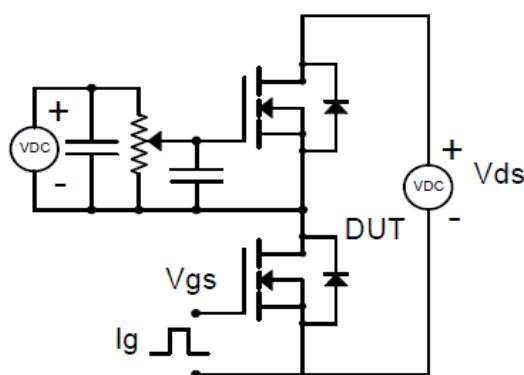
Figure13. Normalized Maximum Transient Thermal Impedance



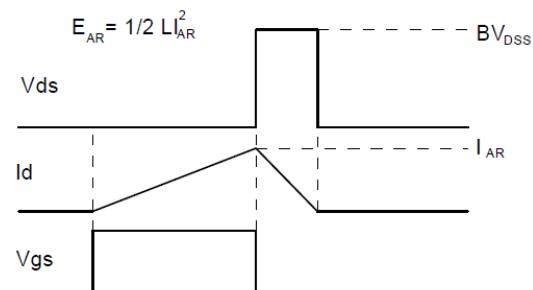
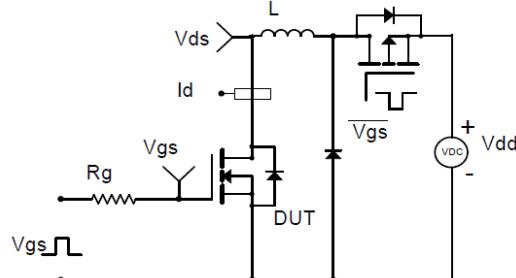
**Resistive Switching Test Circuit & Waveforms**



**Diode Recovery Test Circuit & Waveforms**

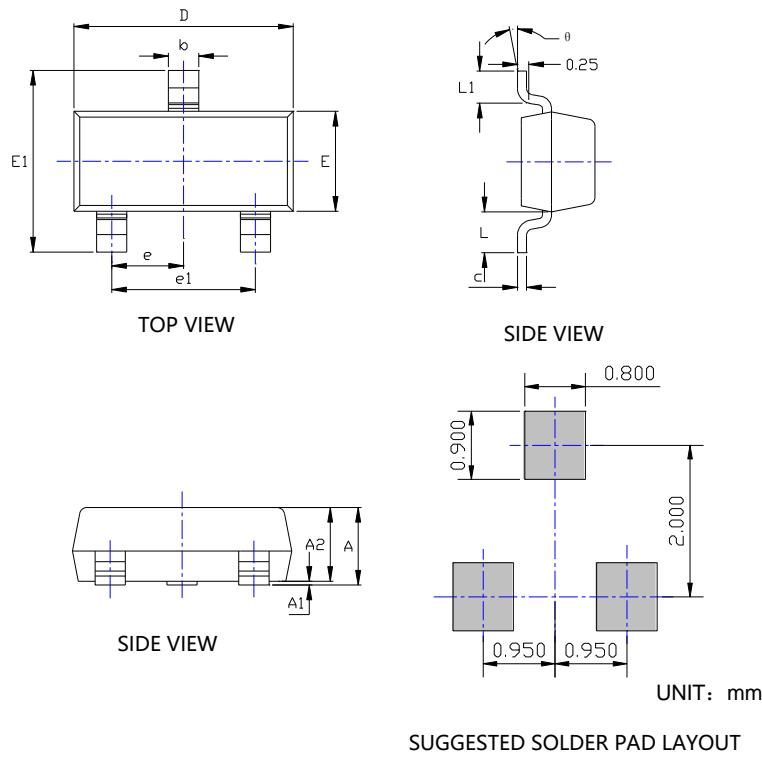


**Gate Charge Test Circuit & Waveform**



**Unclamped Inductive Switching (UIS) Test Circuit & Waveforms**

## ■ SOT-23 Package information



SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037 TYP		0.950 TYP	
e1	0.071	0.079	1.800	2.000
L	0.022 REF		0.550 REF	
L1	0.012	0.020	0.300	0.500
theta	0°	8°	0°	8°

## NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

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